- 12-Bit Voltage Output DAC
- Single Supply 2.7-V to 5.5-V Operation
- Separate Analog and Digital Supplies
- ±0.4 LSB Differential Nonlinearity (DNL),
   ±1.5 LSB Integral Nonlinearity (INL)
- Programmable Settling Time vs Power Consumption:

1  $\mu$ s/4.2 mW in Fast Mode, 3.5  $\mu$ s/1.2 mW in Slow Mode

- 8-Bit μController Compatible Interface (8+4 Bit)
- Power-Down Mode (50 nW)
- Rail-to-Rail Output Buffer
- Synchronous or Asynchronous Update
- Monotonic Over Temperature

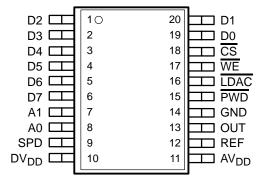
### description

The TLV5613 is a 12-bit voltage output digital-to-analog converter (DAC) with a 8-bit microcontroller compatible parallel interface. The 8 LSBs, the 4 MSBs and 3 control bits are written using three different addresses. Developed for a wide range of supply voltages, the TLV5613 can be operated from 2.7 V to 5.5 V.

## applications

- Digital Servo Control Loops
- Battery Powered Test Instruments
- Digital Offset and Gain Adjustment
- Industrial Process Control
- Speech Synthesis
- Machine and Motion Control Devices
- Mass Storage Devices

# DW OR PW PACKAGE (TOP VIEW)



The resistor string output voltage is buffered by a x2 gain rail-to-rail output buffer. The buffer features a Class A (slow mode: AB) output stage to improve stability and reduce settling time. The programmable settling time of the DAC allows the designer to optimize speed versus power dissipation. The settling time can be chosen by the control bits within the 16-bit data word.

Implemented with a CMOS process, the device is designed for single supply operation from 2.7 V to 5.5 V. It is available in 20 pin SOIC in standard commercial and industrial temperature ranges.

#### **AVAILABLE OPTIONS**

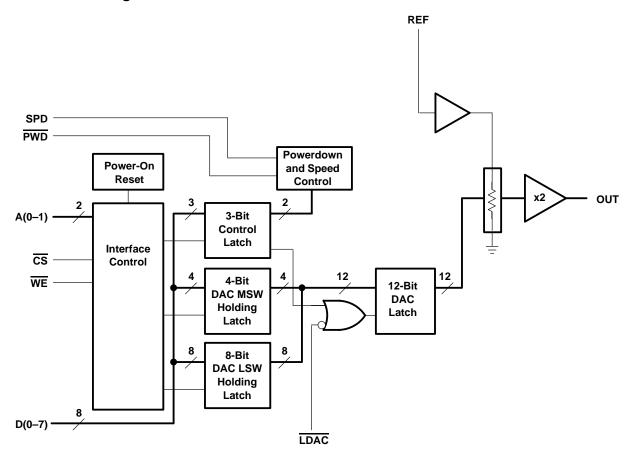
PACKAGE						
TA	SMALL OUTLINE (DW)	TSSOP (PW)				
0°C to 70°C	TLV5613CDW	TLV5613CPW				
-40°C to 85°C	TLV5613IDW	TLV5613IPW				



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



# functional block diagram



# **Terminal Functions**

TERMINA	\L	1/0	DESCRIPTION
NAME	NO.	"	DESCRIPTION
$AV_{DD}$	11		Analog positive power supply
A0	8	I	Address input
A1	7	I	Address input
CS	18	I	Chip select. Digital input active low, used to enable/disable inputs
$DV_{DD}$	10		Digital positive power supply
D0 (LSB) - D7 (MSB)	1–6, 19, 20	I	Data input
LDAC	16	I	Load DAC. Digital input active low, used to load DAC output
OUT	13	0	DAC analog voltage output
PWD	15	ı	Power down. Digital input active low
REF	12	ı	Analog reference voltage input
SPD	9	I	Speed select. Digital input
GND	14		Ground
WE	17	I	Write enable. Digital input active low, used to latch data



# TLV5613 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

SLAS174B - DECEMBER 1997 - REVISED NOVEMBER 2000

# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage (DV <sub>DD</sub> , AV <sub>DD</sub> to GND)	
Supply voltage difference, AV <sub>DD</sub> to DV <sub>DD</sub>	
Reference input voltage range	$\dots$ – 0.3 V to AV <sub>DD</sub> + 0.3 V
Digital input voltage range to GND	$\dots$ - 0.3 V to DV <sub>DD</sub> + 0.3 V
Operating free-air temperature range, T <sub>A</sub> : TLV5613C	0°C to 70°C
TLV5613I	–40°C to 85°C
Storage temperature range, T <sub>stq</sub>	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage Van	5-V Supply	4.5	5	5.5	V
Supply voltage, V <sub>DD</sub>	3-V Supply	2.7	3	3.3	V
Supply voltage difference, $\Delta V_{DD} = AV_{DD} - D$	OV <sub>DD</sub>	-2.8	0	2.8	V
Power on reset, POR		0.55		2	V
High-level digital input voltage, VIH	DV <sub>DD</sub> = 2.7 V to 5.5 V	2			V
Low-level digital input voltage, V <sub>IL</sub>	DV <sub>DD</sub> = 2.7 V to 5.5 V			0.8	V
Peterone voltage V eta PEEIN terminal	5-V Supply (see Note 1)	GND	2.048	AV <sub>DD</sub> -1.5	V
Reference voltage, V <sub>ref</sub> to REFIN terminal	3-V Supply (see Note 1)	GND	1.024	AV <sub>DD</sub> -1.5	V
Load resistance, R <sub>L</sub>		2			kΩ
Load capacitance, CL				100	pF
Operating free-air temperature, T <sub>Δ</sub>	TLV5613C	0		70	°C
Operating nee-all temperature, 14	TLV5613I	-40		85	°C

NOTE 1: Due to the x2 output buffer, a reference input voltage  $\geq (V_{DD} - 0.4)/2$  causes clipping of the transfer function.



# TLV5613

# 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

SLAS174B - DECEMBER 1997 - REVISED NOVEMBER 2000

electrical characteristics over recommended operating free-air temperature range, supply voltages, and reference voltages (unless otherwise noted)

# power supply

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT		
			\/ F\/		V <sub>DD</sub> = 5 V	Fast		1.6	3	mA
l <sub>nn</sub>	Power cupply current	All inputs = GND or DV <sub>DD</sub> ,	νDD = 3 ν	Slow		0.5	1.3	mA		
ססי			\/nn - 2 \/	Fast		1.4	2.7	mA		
			$V_{DD} = 3 V$	Slow		0.4	1.1	mA		
	Power down supply current	See Figure 14				0.01	10	μΑ		
PSRR	Power supply rejection ratio	Zero scale,	See Note 2			-65		dB		
FSKK	Fower supply rejection ratio	Full scale,	See Note 3			-65		uБ		

NOTES: 2. Power supply rejection ratio at zero scale is measured by varying AV<sub>DD</sub> and is given by:

 $PSRR = 20 \log [(E_{ZS}(AV_{DD}max) - E_{ZS}(AV_{DD}min))/AV_{DD}max]$ 

3. Power supply rejection ratio at full scale is measured by varying AV<sub>DD</sub> and is given by:  $PSRR = 20 log [(E_G(AV_{DD}max) - E_G(AV_{DD}min))/AV_{DD}max]$ 

# static DAC specifications

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
	Resolution	V <sub>ref</sub> (REFIN) = 2.048 V, 1.024 V		12			bits
	Integral nonlinearity (INL), end point adjusted	V <sub>ref</sub> (REFIN) = 2.048 V, 1.024 V,	See Note 4		±1.5	±4	LSB
	Differential nonlinearity (DNL)	V <sub>ref</sub> (REFIN) = 2.048 V, 1.024 V,	See Note 5		±0.4	± 1	LSB
EZS	Zero-scale error (offset error at zero scale)	V <sub>ref</sub> (REFIN) = 2.048 V, 1.024 V,	See Note 6		±3	±20	mV
	Zero-scale-error temperature coefficient	V <sub>ref(REFIN)</sub> = 2.048 V, 1.024 V,	See Note 7		3		ppm/°C
EG	Gain error	Vref(REFIN) = 2.048 V, 1.024 V,	See Note 8		±0.25	±0.5	% of FS voltage
	Gain error temperature coefficient	Vref(REFIN) = 2.048 V, 1.024 V,	See Note 9		1		ppm/°C

- NOTES: 4. The relative accuracy or integral nonlinearity (INL) sometimes referred to as linearity error, is the maximum deviation of the output from the line between zero and full scale excluding the effects of zero code and full-scale errors.
  - 5. The differential nonlinearity (DNL) sometimes referred to as differential error, is the difference between the measured and ideal 1 LSB amplitude change of any two adjacent codes. Monotonic means the output voltage changes in the same direction (or remains constant) as a change in the digital input code.
  - 6. Zero-scale error is the deviation from zero voltage output when the digital input code is zero.
  - 7. Zero-scale-error temperature coefficient is given by:  $E_{ZS}$  TC =  $[E_{ZS}$  ( $T_{max}$ )  $E_{ZS}$  ( $T_{min}$ )]/ $V_{ref} \times 10^6$ /( $T_{max}$   $T_{min}$ ).
  - 8. Gain error is the deviation from the ideal output ( $V_{ref} 1$  LSB) with an output load of 10 k $\Omega$  excluding the effects of the zero-error.
  - 9. Gain temperature coefficient is given by:  $E_G TC = [E_G(T_{max}) E_G(T_{min})]/V_{ref} \times 10^6/(T_{max} T_{min})$ .

## output specifications

	PARAMETER	TEST CONDITIO	MIN	TYP	MAX	UNIT	
VO	Output voltage	$R_L = 10 \text{ k}\Omega$		0		AV <sub>DD</sub> -0.4	V
	Output load regulation accuracy	V <sub>O(OUT)</sub> = 4.096 V,	$R_L = 2 k\Omega$ ,		0.1	0.29	% of FS voltage
loos( )	Output short circuit source current	Vo(out) = 0 V input all 1s	$AV_{DD} = 5 V$		-100		mA
<sup>I</sup> OSC(source)	Output short circuit source current	$V_{O(OUT)} = 0 V$ , input all 1s	$AV_{DD} = 3 V$		-25		IIIA
logo(-:-I)	Output short circuit sink current	$R_1 = 100 \Omega$ , input all 1s	$AV_{DD} = 5 V$		-10		mA
IOSC(sink)	Output short circuit sink current	11C = 100 sz, iliput ali 13	$AV_{DD} = 3 V$		-10		ША



electrical characteristics over recommended operating free-air temperature range, supply voltages, and reference voltages (unless otherwise noted)

# reference input (REFIN)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
V <sub>ref</sub>	Input voltage reference	See Note 10		0		AV <sub>DD</sub> -1.5	V
Ri	Input resistance			10		МΩ	
Ci	Input capacitance			5		pF	
	Reference input bandwidth	PEE - 0.2 V + 1.024 V do	Fast mode		1.6		MHz
	Reference input bandwidth	REP = 0.2 Vpp + 1.024 V dC	REF = 0.2 V <sub>pp</sub> + 1.024 V dc Slow mode		1		MHz
	Reference feed through	REF = 1 V <sub>pp</sub> at 1 kHz + 1.024 V See Note 10	dc,		-60		dB

NOTES: 10. Reference feedthrough is measured at the DAC output with an input code = 0x000.

## digital inputs

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
lН	High-level digital input current	$V_I = DV_{DD}$			1	μΑ
IլL	Low-level digital input current	V <sub>I</sub> = 0 V	-1			μΑ
Ci	Input capacitance			8		pF

operating characteristics over recommended operating free-air temperature range, supply voltages, and reference voltages (unless otherwise noted)

### analog output dynamic performance

	PARAMETER	TES	TEST CONDITIONS			TYP	MAX	UNIT
4	Output action time full code	$R_L = 10 \text{ k}\Omega$ ,	See Note 11	Fast		1	3	
ts(FS)	Output settling time, full scale	$C_{L}^{-} = 100 \text{ pF},$		Slow		3.5	7	μs
+ (==)	Output pattling time, and to ende	$R_L = 10 \text{ k}\Omega$ ,	See Note 12	Fast		0.5	1.5	
ts(CC)	Output settling time, code-to-code	C <sub>L</sub> = 100 pF,		Slow		1	2	μs
SR	Slew rate	$R_L$ = 10 kΩ, See Note 13	See Note 13	Fast		8		V/µs
36	Siew rate	$C_L = 100 pF$ ,	C <sub>L</sub> = 100 pF,			1.5		ν/μ5
	Glitch energy	Code-to-code tr	ansition			1		nV-s
S/N	Signal-to-noise				65	78		
S/(N+D)	Signal-to-noise + distortion	f <sub>S</sub> = 480 KSPS,	$f_S = 480 \text{ KSPS}, f_{out} = 1 \text{ kHz},$		58	69		dB
THD	Total harmonic distortion	$R_L = 10 \text{ k},$	$C_L = 100  pF$			-68	-60	ub
	Spurious free dynamic range	7			60	72	·	

- NOTES: 11. Settling time is the time for the output signal to remain within  $\pm 0.5$  LSB of the final measured value for a digital input code change of 0x020 to 0x3FF or 0x3FF to 0x020.
  - 12. Settling time is the time for the output signal to remain within  $\pm$  0.5 LSB of the final measured value for a digital input code change of one count. The max time applies to code changes near zero scale or full scale.
  - 13. Slew rate determines the time it takes for a change of the DAC output from 10% to 90% full-scale voltage.



# timing requirements

# digital inputs

		MIN	NOM	MAX	UNIT
t <sub>su(D)</sub>	Setup time, data ready before positive WE edge	9			ns
t <sub>su(CS-WE)</sub>	Setup time, CS low before positive WE edge	13			ns
t <sub>su(A)</sub>	Setup time, address bits A0, A1	17			ns
<sup>t</sup> h(D)	Hold time, data held after positive WE edge	0			ns
t <sub>su(WE-LD)</sub>	Setup time, positive WE edge before LDAC low	0			ns
tw(WE)	Pulse duration, WE high	25			ns
tw(LD)	Pulse duration, LDAC low	25			μs

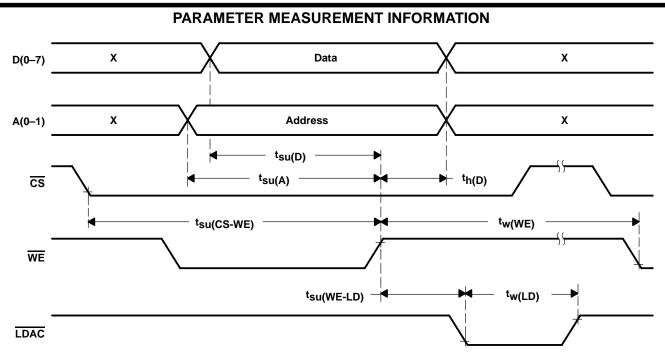


Figure 1. Timing Diagram

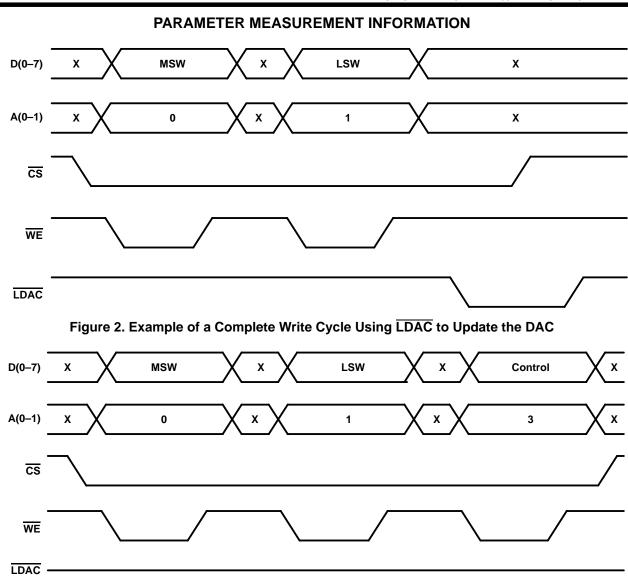
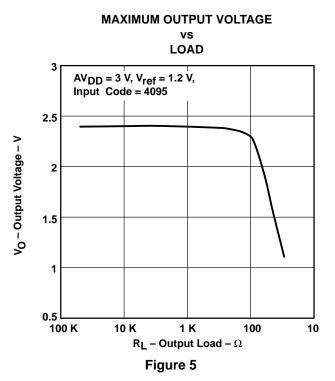
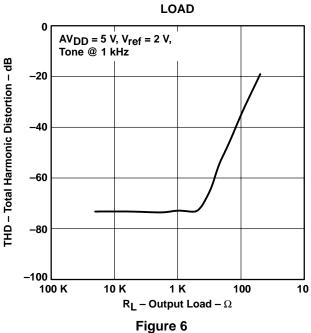


Figure 3. Example of a Complete Write Cycle Using the Control Word to Update the DAC

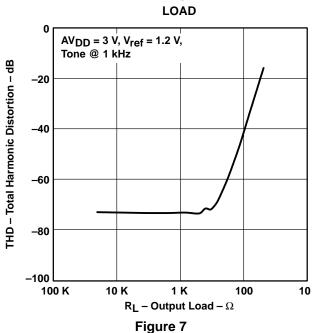
# **MAXIMUM OUTPUT VOLTAGE** vs LOAD $AV_{DD} = 5 \text{ V}, V_{ref} = 2 \text{ V},$ Input Code = 4095 V<sub>O</sub> - Output Voltage - V 3.5 3 2.5 2 1.5 1 K 100 K 10 K 100 10 $R_L$ – Output Load – $\Omega$ Figure 4

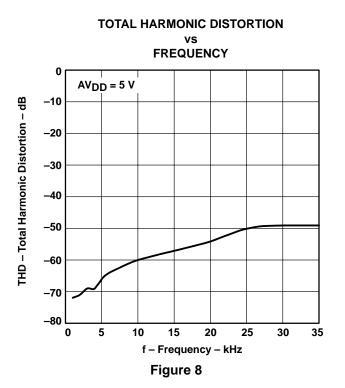


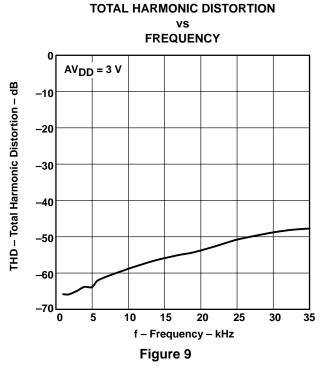


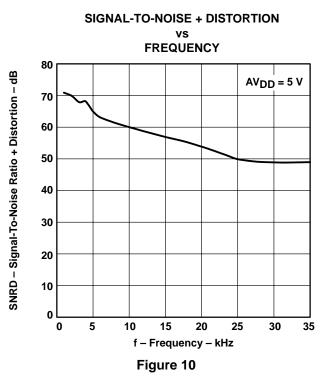


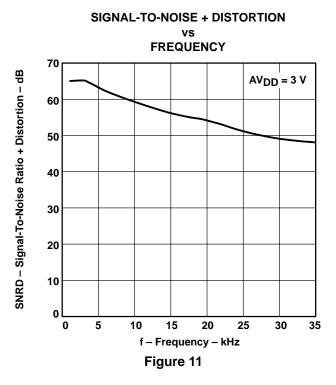
# TOTAL HARMONIC DISTORTION vs











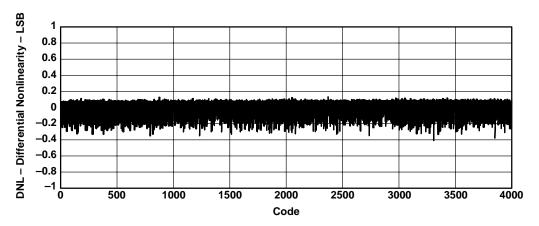


Figure 12. Differential Nonlinearity

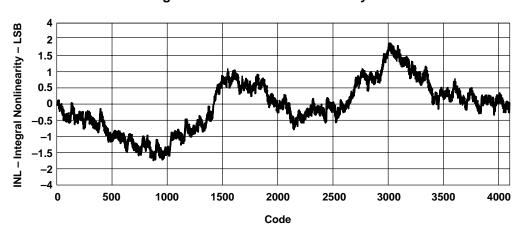
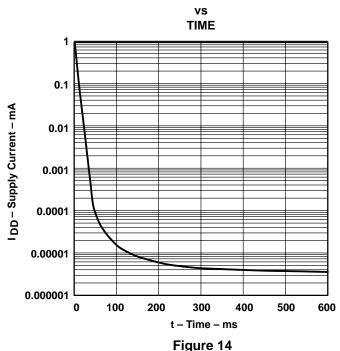


Figure 13. Integral Nonlinearity



#### **POWER DOWN SUPPLY CURRENT**



## **APPLICATION INFORMATION**

# general function

The TLV5613 is a 12-bit, single supply DAC, based on a resistor string architecture. It consists of a parallel interface, speed and power down control logic, a resistor string and a rail-to-rail output buffer. The output voltage (full scale determined by reference) is given by:

2 REF 
$$\frac{\text{CODE}}{0 \times 1000}$$
 [V]

Where REF is the reference voltage and CODE is the digital input value, range 0x000 to 0xFFF. A power on reset initially puts the internal latches to a defined state (all bits zero).

# parallel interface

The device latches data on the positive edge of  $\overline{WE}$ . It must be enabled with  $\overline{CS}$  low. Whether the data is written to one of the DAC holding latches (MSW, LSW) or the control register, depends on the address bits A1 and A0. LDAC low updates the DAC with the value in the holding latch. LDAC is an asynchronous input and can be held low, if a separate update is not necessary. Two more asynchronous inputs, SPD and PWD control the settling times and the power down mode:

SPD: Speed control  $1 \rightarrow \text{fast mode}$  $0 \rightarrow slow mode$ PWD: Power control  $1 \rightarrow \text{normal operation}$  $0 \rightarrow power down$ 



# **APPLICATION INFORMATION**

It is also possible to program the different modes (fast, slow, power down) and the DAC update latch using the control register. The following tables list the possible combination of the control signals and control bits.

PIN	BIT	MODE
SPD	SPD	WIODE
0	0	Slow
0	1	Fast
1	0	Fast
1	1	Fast

PIN	BIT	POWER					
PWD	PWD	POWER					
0	0	Down					
0	1	Down					
1	0	Normal					
1	1	Down					

PIN	BIT	LATCH				
LDAC	RLDAC	LAICH				
0	0	Transparent				
0	1	Transparent				
1	0	Hold				
1	1	Transparent				

# data format

The TLV5613 writes data either to one of the DAC holding latches or to the control register depending on the address bits A1 and A0.

# **ADDRESS BITS**

A1	A0	REGISTER
0	0	DAC LSW holding
0	1	DAC MSW holding
1	0	Reserved
1	1	Control

D7	D6	D5	D4	D3	D2	D1	D0
X	Х	Х	Х	X	RLDAC	PWD	SPD

X: Don't care

 $\begin{array}{lll} \text{SPD: Speed control bit} & & 1 \rightarrow \text{fast mode} \\ \text{PWD: Power control bit} & & 1 \rightarrow \text{power down} \\ \end{array}$ 

0 → slow mode0 → normal operation

RLDAC: Load DAC latch  $1 \rightarrow$  latch transparent

 $0 \rightarrow DAC$  latch controlled by  $\overline{LDAC}$  pin



#### APPLICATION INFORMATION

# layout considerations

To achieve the best performance, it is recommended to have separate power planes for GND,  $AV_{DD}$ , and  $DV_{DD}$ . Figure 15 shows how to lay out the power planes for the TLV5613. As a general rule, digital and analog signals should be separated as wide as possible. To avoid crosstalk, analog and digital traces must not be routed in parallel. The two positive power planes ( $AV_{DD}$  and  $DV_{DD}$ ) should be connected together at one point with a ferrite bead.

A 100-nF ceramic low series inductance capacitor between DV<sub>DD</sub> and GND and a  $1-\mu$ F tantalum capacitor between AV<sub>DD</sub> and GND as close as possible to the supply pins are recommended for optimal performance.

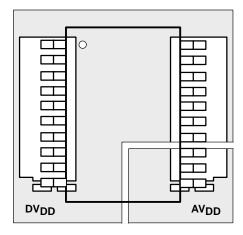


Figure 15. TLV5613 Board Layout

#### linearity, offset, and gain error using single end supplies

When an amplifier is operated from a single supply, the voltage offset can still be either positive or negative. With a positive offset, the output voltage changes on the first code change. With a negative offset the output voltage may not change with the first code depending on the magnitude of the offset voltage.

The output amplifier attempts to drive the output to a negative voltage. However, because the most negative supply rail is ground, the output cannot drive below ground and clamps the output at 0 V.

The output voltage remains at zero until the input code value produces a sufficient positive output voltage to overcome the negative offset voltage, resulting in the transfer function shown in Figure 16.

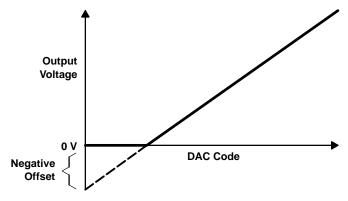


Figure 16. Effect of Negative Offset (Single Supply)



# 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

SLAS174B - DECEMBER 1997 - REVISED NOVEMBER 2000

#### APPLICATION INFORMATION

This offset error, not the linearity error, produces this breakpoint. The transfer function would have followed the dotted line if the output buffer could drive below the ground rail.

For a DAC, linearity is measured between zero input code (all inputs 0) and full scale code (all inputs 1) after offset and full scale are adjusted out or accounted for in some way. However, single supply operation does not allow for adjustment when the offset is negative due to the breakpoint in the transfer function. So the linearity is measured between full scale code and the lowest code that produces a positive output voltage.

# TLV5613 interfaced to an Intel MCS®251 controller

The circuit in Figure 17 shows how to interface the TLV5613 to an Intel MCS®251 microcontroller. The address bus and the data bus of the controller are multiplexed on port 0 (non page mode) to save port pins. To separate the address bits and the data bits, the controller provides a dedicated signal, address latch enable (ALE), which is connected to a latch at port 0.

An address decoder is required to generate the chip select signal for the TLV5613. In this example, a simple 3-to-8 decoder (74AC138) is used for the interface as shown in Figure 17. The DAC is memory mapped at addresses 0x8000/1/2/3 within the data memory address space and mirrored every 32 address locations (0x8020/1/2/3, 0x8040/1/2/3, etc.). In a typical microcontroller system, programmable logic should be used to generate the chip select signals for the entire system.

The data pins and the WE pin of the TLV5613 can be connected directly to the multiplexed address and data bus and the WR signal of the controller.

LDAC is held high so that the output voltage is updated using the RLDAC bit in the control register. Hardware power down mode is deactivated permanently by pulling PWD to DV<sub>DD</sub>.

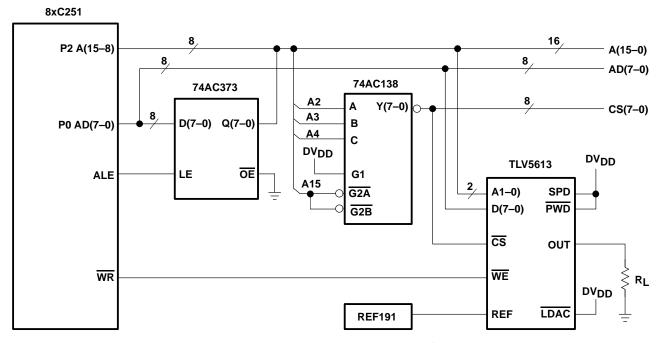


Figure 17. TLV5613 Interfaced to an Intel MCS®251 Controller

MCS is a registered trademark of Intel Corporation



#### APPLICATION INFORMATION

#### software

In the following example, the code generates a waveform at 500 KSPS with 500 samples stored in a table within the program memory space of the microcontroller. The period of the waveform is 1 ms.

The waveform data is located in the program memory space from address 01000h to address 013E8h  $(2 \times 500 = 1000 = 03E8h)$  beginning with the MSW of the first 16-bit word (the 4 MSBs are ignored), followed by the LSW. Two bytes are required for each DAC word (the table is not shown in the code example).

The program consists of two parts:

- A main routine, which is executed after reset and which initializes the timer and the interrupt system of the microcontroller.
- An interrupt service routine, which reads a new value from the waveform table and writes it to the DAC.

This example uses timer 0 in mode 3 (8-bit timer with auto reload). The clock of the timer is derived from the system clock and has a frequency of  $f_{OSC}/12$ . The timer overrun frequency  $f_{tim}$  is given by the following equation:

$$f_{tim} = \frac{f_{OSC}}{12(256-Reload)}$$
 and the reload value is given by Reload = 256-  $\frac{f_{OSC}}{12 f_{tim}}$ 

To get a timer overrun frequency of 500 kHz at a system clock of 24 MHz, the reload value is:

Reload = 
$$256 - \frac{24}{12 \times 0.5} = 256 - 4 = 252 = 0$$
FCh

With this value, the timer generates an interrupt every  $2\,\mu s$ . The corresponding service routine  ${\tt T0\_isr}$  reads a sample from program memory and writes it to the DAC. First, it disables the update of the DAC output by clearing the RLDAC bit in the control register. Then it reads the MSW and the LSW from the waveform table and stores it in the MSW and LSW register of the TLV5613. The write cycle is completed by setting the RLDAC bit, which updates the DAC output. At the end of the interrupt service routine, the pointer to the waveform samples is increased and is checked to determine if it has reached the end of the table. If the pointer has reached the end of the table, the pointer is set to the start address of the table.

# TLV5613 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

SLAS174B - DECEMBER 1997 - REVISED NOVEMBER 2000

#### APPLICATION INFORMATION

;\* Title : Waveform generation with TLV5613 ;\* Version: 1.0 ; \* MCU : Intel MCS®251, MCS®51 ;\* © 1998 Texas Instruments Inc. TABLE\_START EQU 01000h ;start address of waveform data TABLE\_END\_H EQU 013h ; high byte - end address of waveform data TABLE\_END\_L EQU 0E8h ; low byte - end address of waveform data RELOAD EQU 0FCh ;timer reload value ORG 00000h ;entry point JMP main ; jump to main program ORG 0000bh ;timer0 (T0) interrupt vector JMP T0\_isr ; jump to TO interrupt service routine ;-----;main: setup timer and interrupt, loop forever ;----main: CLR A MOV A, IEO disable all interrupts; CLR TCON.4 ;stop T0 MOV A, #002h MOV TMOD, A ;set T0 to auto reload mode MOV A, #RELOAD MOV THO, A ;set T0 reload value MOV TLO, A ;set T0 start value MOV P2, #080h ;set A15 of address bus to select DAC MOV DPTR, #TABLE\_START ;set data pointer to start of wave form data SETB IE0.1 ;enable T0 interrupt SETB IE0.7 ;enable interrupts SETB TCON.4 ;start T0 idle\_loop: SJMP idle\_loop ;loop forever



#### **APPLICATION INFORMATION**

;-----

;T0\_isr: will be called on every timer interrupt.

ifetches a new 16-bit value from program memory space and writes it

;to the DAC. If end of table is reached, sets DPTR to table start addr.

TO\_isr: MOV RO, #003h ;select DAC control register

MOV A, #001h ;RLDAC=0, PWD=0, SPD=1

;no DAC update, normal operation, fast mode

MOVX @RO, A ;write Accu to DAC control register

MOV RO, #001h ;select DAC MSW register

CLR A

MOVC A, @A+DPTR ;get MSW from code memory

MOVX @R0, A ;write Accu to DAC MSW register

INC DPTR ;set DPTR to LSW data

MOV R0, #000h ;select DAC LSW register

CLR A

MOVC A, @A+DPTR ;get LSW from code memory

MOVX @RO, A ;write Accu to DAC LSW register

MOV RO, #003h ;select DAC control register (to update DAC)

MOV A, #005h ;DAC update, normal operation, fast mode

MOVX @RO, A ;write Accu to DAC control register

INC DPTR ;set DPTR to next MSW

;test end of table

MOV A, DPL

CJNE A, #TABLE\_END\_L, T0\_isr\_end

MOV A, DPH

CJNE A, #TABLE\_END\_H, T0\_isr\_end

MOV DPTR, #TABLE\_START ; end of table reached -> start again

T0\_isr\_end: RETI

END



# **APPLICATION INFORMATION**

# definitions of specifications and terminology

# integral nonlinearity (INL)

The relative accuracy or integral nonlinearity (INL), sometimes referred to as linearity error, is the maximum deviation of the output from the line between zero and full scale excluding the effects of zero code and full-scale errors.

#### differential nonlinearity (DNL)

The differential nonlinearity (DNL), sometimes referred to as differential error, is the difference between the measured and ideal 1 LSB amplitude change of any two adjacent codes. Monotonic means the output voltage changes in the same direction (or remains constant) as a change in the digital input code.

#### zero-scale error (E<sub>7S</sub>)

Zero-scale error is defined as the deviation of the output from 0 V at a digital input value of 0.

#### gain error (E<sub>G</sub>)

Gain error is the error in slope of the DAC transfer function.

# signal-to-noise ratio + distortion (SINAD)

Signal-to-noise ratio + distortion is the ratio of the rms value of the output signal to the rms sum of all other spectral components below the Nyquist frequency, including harmonics but excluding dc. The value for SINAD is expressed in decibels.

#### spurious free dynamic range (SFDR)

Spurious free dynamic range is the difference between the rms value of the output signal and the rms value of the spurious signal within a specified bandwidth. The value for SFDR is expressed in decibels.

#### total harmonic distortion (THD)

Total harmonic distortion is the ratio of the rms sum of the first six harmonic components to the rms value of the fundamental signal and is expressed in decibels.



www.ti.com 30-Jun-2025

#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ MSL rating/ Ball material Peak reflow		Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
TLV5613CDW	Active	Production	SOIC (DW)   20	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV5613C
TLV5613CDW.A	Active	Production	SOIC (DW)   20	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV5613C
TLV5613CPW	Active	Production	TSSOP (PW)   20	70   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TV5613
TLV5613CPW.A	Active	Production	TSSOP (PW)   20	70   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TV5613
TLV5613IDW	Active	Production	SOIC (DW)   20	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLV5613I
TLV5613IDW.A	Active	Production	SOIC (DW)   20	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLV5613I
TLV5613IPW	Active	Production	TSSOP (PW)   20	70   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5613
TLV5613IPW.A	Active	Production	TSSOP (PW)   20	70   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5613

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

# **PACKAGE OPTION ADDENDUM**

www.ti.com 30-Jun-2025

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 23-May-2025

# **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TLV5613CDW	DW	SOIC	20	25	506.98	12.7	4826	6.6
TLV5613CDW.A	DW	SOIC	20	25	506.98	12.7	4826	6.6
TLV5613CPW	PW	TSSOP	20	70	530	10.2	3600	3.5
TLV5613CPW.A	PW	TSSOP	20	70	530	10.2	3600	3.5
TLV5613IDW	DW	SOIC	20	25	506.98	12.7	4826	6.6
TLV5613IDW.A	DW	SOIC	20	25	506.98	12.7	4826	6.6
TLV5613IPW	PW	TSSOP	20	70	530	10.2	3600	3.5
TLV5613IPW.A	PW	TSSOP	20	70	530	10.2	3600	3.5

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025. Texas Instruments Incorporated